

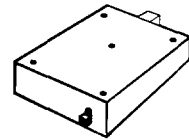
## The RF Line Linear Power Amplifier

... a solid state Class A amplifier specifically designed for TV transposers and transmitters. This amplifier incorporates microstrip technology and discrete linear push-pull transistors with gold metallization and diffused emitter ballast resistors to enhance ruggedness and reliability.

- 470–860 MHz
- 20 W —  $P_{out}$
- 26.5 V —  $V_{CC}$
- 8.5 dB Typ Gain, Class A

**ATV5030**

**20 W — 470–860 MHz  
 LINEAR  
 POWER AMPLIFIER**



**CASE 389B-02, STYLE 1  
 (AMR)**

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector Voltage Supply	$V_{CC}$	27	Vdc
Supply Current	$I_{CC}$	4	Adc
Operating Temperature Range (Note 1)	$T_C$	-20 to +70	°C
Storage Temperature Range	$T_{stg}$	-40 to +100	°C

**ELECTRICAL CHARACTERISTICS** ( $T_C = 50^\circ\text{C}$ , 50  $\Omega$  system,  $V_{CC} = 26.5\text{ V}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Bandwidth	BW	470	—	860	MHz
Power Gain ( $P_{ref} = 20\text{ W}$ , 3 tones)	$G_p$	7.5	8.5	—	dB
Power Output @ 1 dB Gain Compression (Reference to $P_{out} = 20\text{ W}$ )	$P_{out}(1\text{ dB})$	25	28	—	W
Supply Current ( $P_{out} = 20\text{ W}$ )	$I_{CC}$	—	3.8	—	A
Input Return Loss ( $P_{out} = 20\text{ W}$ )	IRL	15	—	—	dB
Output Return Loss ( $P_{out} = 20\text{ W}$ )	ORL	15	—	—	dB
Load Mismatch ( $P_{ref} = 20\text{ W}$ , 3 tones, $f = 860\text{ MHz}$ , Load VSWR = $\infty:1$ , All Phase Angles)	$\psi$	No degradation in power output			
Gain Flatness ( $P_{ref} = 20\text{ W}$ , 3 tones, BW = 470 to 860 MHz)	$G_r$	—	$\pm 0.5$	$\pm 0.8$	dB
Intermodulation Distortion — 3 tones ( $f = 860\text{ MHz}$ , $V_{CE} = 25.5\text{ V}$ , $P_{ref} = 20\text{ W}$ , Vision Carrier = -7 dB, Sound Carrier = -8 dB, Sideband Signal = -16 dB, Specification TV05001)	IMD <sub>1</sub>	—	-52	-51	dB
Intermodulation Distortion (IDEM) ( $f = 860\text{ MHz}$ , $V_{CE} = 25.5\text{ V}$ , $P_{ref} = 20\text{ W}$ , Vision Carrier = -10 dB, Sound Carrier = -8 dB, Sideband Signal = -16 dB)	IMD <sub>2</sub>	—	-55	-54	dB

Notes: 1. Case Temperature is measured at base plate.

TYPICAL CHARACTERISTICS

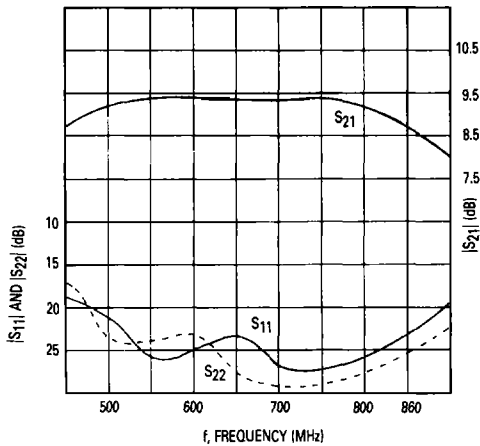


Figure 1. Small-Signal « S » Parameter Magnitude versus Frequency

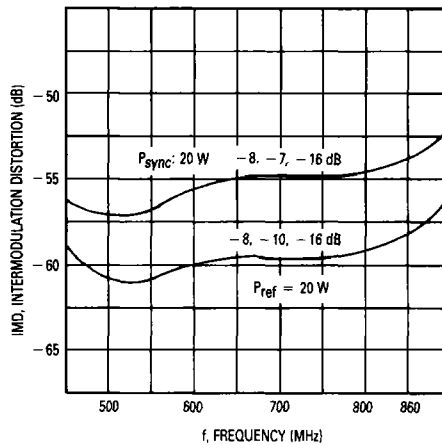


Figure 2. Intermodulation versus Frequency

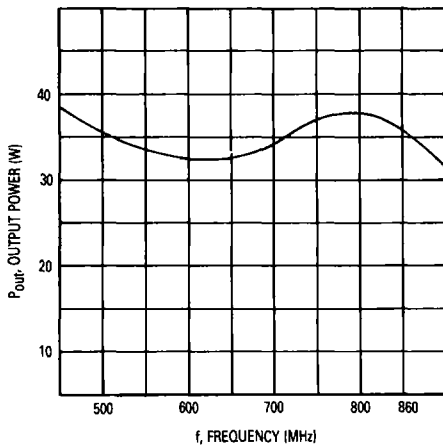


Figure 3. Output Power at 1 dB Gain Compression versus Frequency

\* 3 tones test method:

IMD1: Vision carrier — 8 dB, sound carrier — 7 dB  
Sideband signal — 16 dB; Zero dB corresponds to peak sync level.

IMD2: Vision carrier — 8 dB, sound carrier — 10 dB  
Sideband signal — 16 dB; Zero corresponds to reference level.

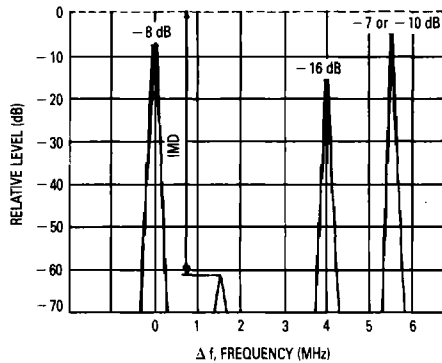
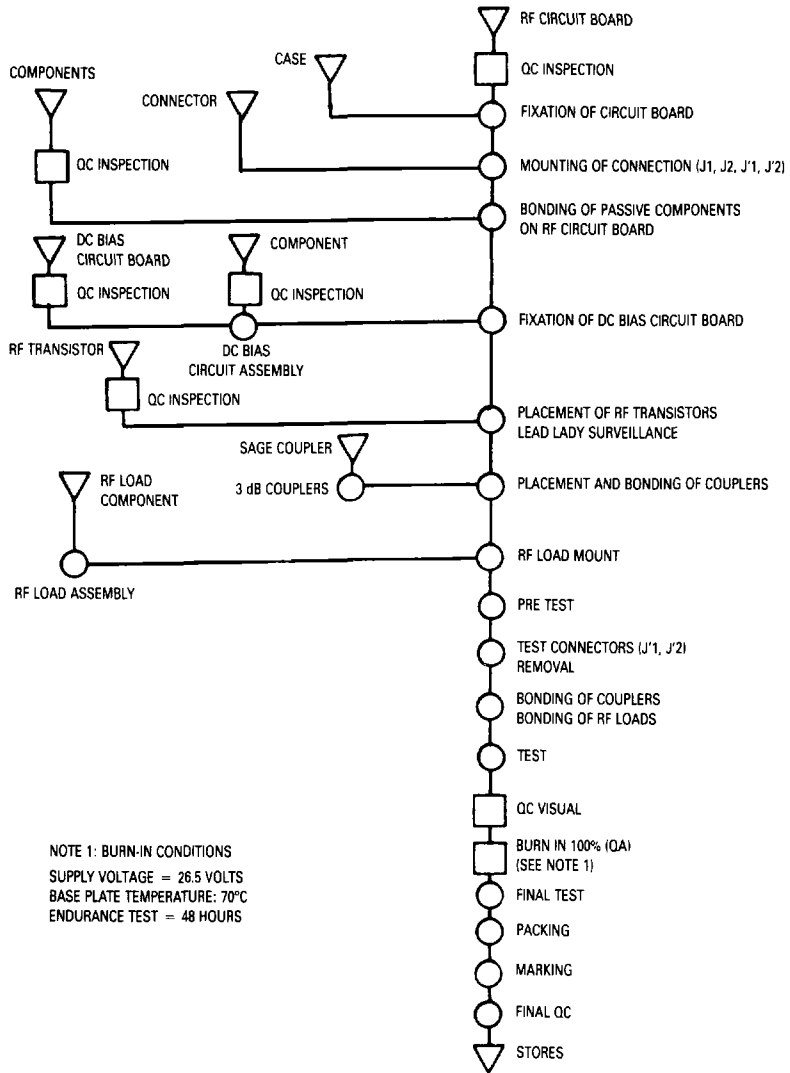


Figure 4. Relative Level versus Frequency

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NOTE 1: BURN-IN CONDITIONS  
 SUPPLY VOLTAGE = 26.5 VOLTS  
 BASE PLATE TEMPERATURE: 70°C  
 ENDURANCE TEST = 48 HOURS

Figure 5. Manufacturing Flow Chart Operation

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